NSN 5961-01-087-5890

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-087-5890 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.224 inches **Overall Diameter:** 0.123 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Clip **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 breakover voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 1.4 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Internal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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